

AiT Semiconductor Inc.

DESCRIPTION

The AO358 is include two high-voltage (30V) OP Amp. The AO358 provide outstanding value for cost-effective applications, with features including low offset (500uA, typical) common-mode input range to ground, and high differential input voltage capability.

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The AO358 design with enhanced features such as unity-gain stability, lower offset voltage of 5mV (Max), and lower quiescent current of 500uA per amplifier (typical), which to provide optimal performance in low voltage and low noise systems.

The AO358 Dual is available in SOP8 and MSOP8 packages.

ORDERING INFORMATION

Package Type	Part Number		
SOP8	MO	AO358M8R	
SPQ: 2,500pcs/Reel	M8	AO358M8VR	
MSOP8	MCO	AO358MS8R	
SPQ: 3,000pcs/Reel	MS8	AO358MS8VR	
Note	V: Halogen free Package		
Note	R: Tape & Reel		
AiT provides all RoHS products			

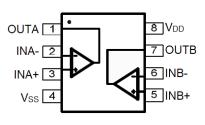
FEATURES

- Single-Supply Operation from +3V to +30V
- Quiescent Current: 500µA per Amplifier (Typ.)
- Unity-gain bandwidth of 1MHz (Typ.)
- Low Offset Voltage: 5mV (Max.)
- Low Input Bias Current: 45nA (Typ.)
- Dual-Supply Operation from ±1.5V to ±15V
- Operating Temperature: -25°C ~ +85°C
- Available in SOP8 and MSOP8 packages

APPLICATION

- Merchant network and server power supply units
- Power supplies and mobile chargers
- Motor control: AC induction, brushed DC, brushless DC, high-voltage, low-voltage, permanent magnet, and stepper motor
- Desktop PC, motherboard, and printers
- Indoor and outdoor air conditioners
- Washers, dryers, and refrigerators
- AC inverters, string inverters, central inverters, and voltage frequency drives
- Uninterruptible power supplies
- Programmable logic controllers
- Electronic point-of sales (POS) systems
- Battery Management Solution
- Transducer Amplifiers, Summing Amplifiers

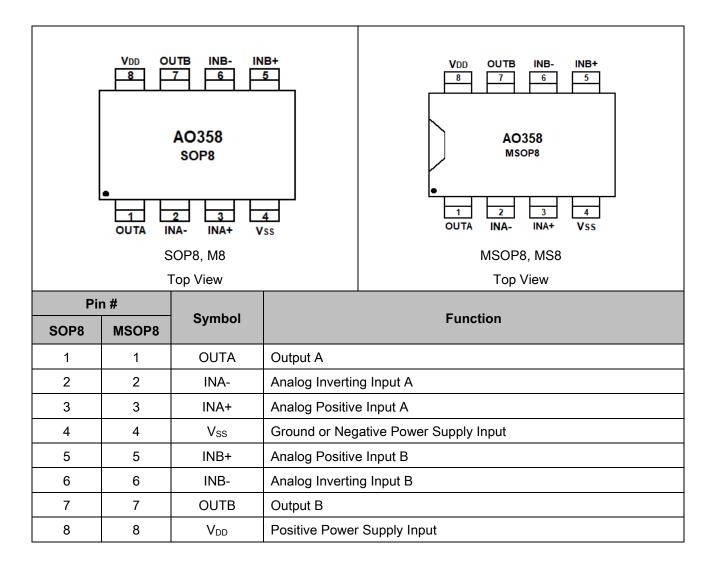
TYPICAL APPLICATION



SOP8/MSOP8



PIN DESCRIPTION





ABSOLUTE MAXIMUM RATINGS

Vcc, Power Supply Voltage	±16V or 32V
V _{I(DIFF)} , Differential Input Voltage	32V
V _I , Input Voltage	-0.3 ~ 32V
TOPR, Operating Temperature Range	-25°C ~ 85°C
T _{STG} , Storage Temperature Range	-65°C ~ 150°C

Stress beyond above listed "Absolute Maximum Ratings" may lead permanent damage to the device. These are stress ratings only and operations of the device at these or any other conditions beyond those indicated in the operational sections of the specifications are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

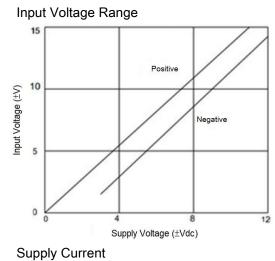
ELECTRICAL CHARACTERISTICS

At V_S = +15V, T_A =25°C, unless otherwise noted.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
INPUT CHARACTERISTICS						
Input Offset Voltage	Vos	V _{CM} = V _S /2	1	0.4	5	mV
Input Bias Current	lв		1	45	-	nA
Input Offset Current	los		-	5	-	nA
Common-Mode Voltage Range	Vсм	Vs = 5.5V	-	-0.1 to 4	-	V
Common-Mode Rejection Ratio	CMRR	V_{CM} = 0V to Vs-1.5V	70	90	-	dB
Open-Loop Voltage Gain	Aol	$R_L = 5k\Omega$, Vo = 1V to 11V	85	100	-	dB
Input Offset Voltage Drift	ΔVos/Δτ			7	-	µV/°C
OUTPUT CHARACTERISTICS						
	Vон	$R_L = 2k\Omega$	-	11	-	V
Output Maltaga Curing from Dail	Vol	$R_L = 2k\Omega$	-	5	20	mV
Output Voltage Swing from Rail	V _{OH}	R _L = 10kΩ	-	12	13	V
	Vol	R _L = 10kΩ	1	5	20	mV
Output Current	ISOURCE	R_L = 10 Ω to V _S /2	1	40	60	mA
Output Current	I _{SINK}		-	40	60	
POWER SUPPLY						
			3	-	-	V
Operating Voltage Range			-	-	30	V
Power Supply Rejection Ratio	PSRR	$V_{\rm S}$ = +5V to +30V, $V_{\rm CM}$ = +0.5V	70	100	-	dB
Quiescent Current/Amplifier	la	Vs=30V, R∟=∞	-	0.5	2.5	mA
DYNAMIC PERFORMANCE						
Gain-Bandwidth Product	GBP		-	1	-	MHz
Slew Rate	SR	G = +1, 2V Output Step	-	0.4	-	V/µs

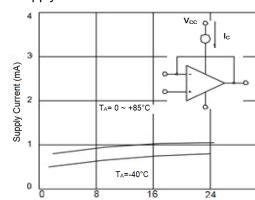


TYPICAL PERFORMANCE CHARACTERISTICS



1.

3.

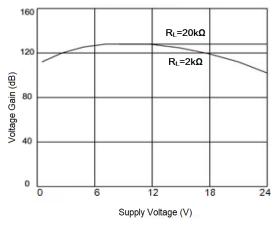




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2. Input Current 100 80 Input Current (nA) Vcc=+30V 60 Vcc=+15V 40 Vcc=+5V 20 0 -50 -25 0 25 50 75 100 Temperature (°C)







DETAILED INFORMATION

AO358 series op amps are unity-gain stable and suitable for a wide range of general-purpose applications.

Power Supply Bypassing and Board Layout

AO358 series operates from a single 3V to 30V supply or dual $\pm 1.5V$ to $\pm 15V$ supplies. For best performance, a 0.1µF ceramic capacitor should be placed close to the V_{DD} pin in single supply operation. For dual supply operation, both V_{DD} and V_{SS} supplies should be bypassed to ground with separate 0.1µF ceramic capacitors.

Low Supply Current

The low supply current (typical 500uA per channel) of AO358 will help to maximize battery life.

Operating Voltage

AO358 operates under wide input supply voltage (3V to 30V). In addition, all temperature specifications apply from -25°C to +85°C. Most behavior remains unchanged throughout the full operating voltage range. These guarantees ensure operation throughout the single Li-Ion battery lifetime.

Capacitive Load Tolerance

The AO358 is optimized for bandwidth and speed, not for driving capacitive loads. Output capacitance will create a pole in the amplifier's feedback path, leading to excessive peaking and potential oscillation. If dealing with load capacitance is a requirement of the application, the two strategies to consider are (1) using a small resistor in series with the amplifier's output and the load capacitance and (2) reducing the bandwidth of the amplifier's feedback loop by increasing the overall noise gain.

Figure 1 shown a unity gain follower using the series resistor strategy. The resistor isolates the output from the capacitance and, more importantly, creates a zero in the feedback path that compensates for the pole created by the output capacitance.

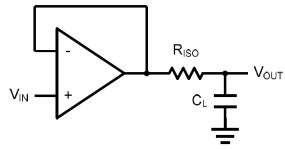


Figure 1. Indirectly Driving a Capacitive Load Using Isolation Resistor



The bigger the R_{ISO} resistor value, the more stable V_{OUT} will be. However, if there is a resistive load R_L in parallel with the capacitive load, a voltage divider (proportional to R_{ISO}/R_L) is formed, this will result in a gain error.

The circuit in Figure 2 is an improvement to the one in Figure 1. R_F provides the DC accuracy by feed-forward the V_{IN} to R_L. C_F and R_{ISO} serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving the phase margin in the overall feedback loop. Capacitive drive can be increased by increasing the value of C_F. This in turn will slow down the pulse response.

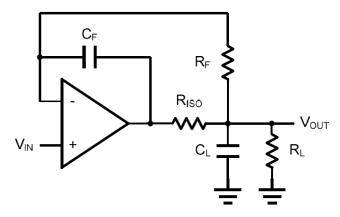


Figure 2. Indirectly Driving a Capacitive Load with DC Accuracy

Typical Application Circuits

Differential amplifier

The differential amplifier allows the subtraction of two input voltages or cancellation of a signal common the two inputs. It is useful as a computational amplifier in making a differential to single-end conversion or in rejecting a common mode signal. Figure 3 shown the differential amplifier using AO358.

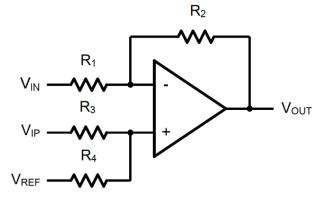


Figure 3. Differential Amplifier



$$V_{OUT} = \left(\frac{R_1 + R_2}{R_3 + R_4}\right) \frac{R_4}{R_1} V_{IN} - \frac{R_2}{R_1} V_{IP} + \left(\frac{R_1 + R_2}{R_3 + R_4}\right) \frac{R_3}{R_1} V_{REF}$$

If the resistor ratios are equal (i.e. $R_1=R_3$ and $R_2=R_4$), then

$$V_{OUT} = \frac{R_2}{R_1} (V_{IP} - V_{IN}) + V_{REF}$$

Low Pass Active Filter

The low pass active filter is shown in Figure 4. The DC gain is defined by $-R_2/R_1$. The filter has a -20dB/decade roll-off after its corner frequency $f_c=1/(2\pi R_3C_1)$.

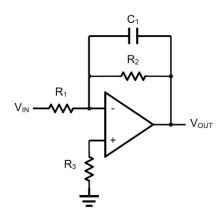


Figure 4. Low Pass Active Filter

Instrumentation Amplifier

The triple AO358 can be used to build a three-op-amp instrumentation amplifier as shown in Figure 5. The amplifier in Figure 5 is a high input impedance differential amplifier with gain of R_2/R_1 . The two differential voltage followers assure the high input impedance of the amplifier.

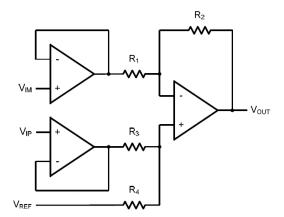
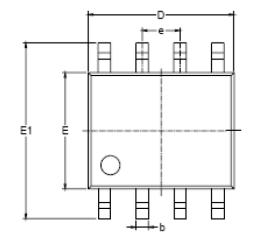


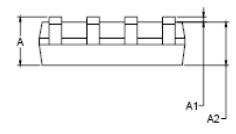
Figure 5. Instrument Amplifier



PACKAGE INFORMATION

Dimension in SOP8 (Unit: mm)



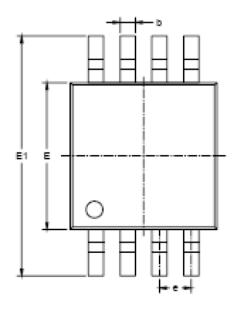




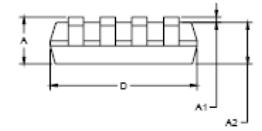
Symbol	Millimeters		Inches		
	Min.	Max.	Min.	Max.	
A	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
с	0.170	0.250	0.006	0.010	
D	4.700	5.100	0.185	0.200	
E	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
е	1.27 BSC		0.050 BSC		
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	



Dimension in MSOP8 (Unit: mm)







Symbol	Millimeters		Inches		
	Min.	Max.	Min.	Max.	
А	0.820	1.100	0.032	0.043	
A1	0.020	0.150	0.001	0.006	
A2	0.750	0.950	0.030	0.037	
b	0.250	0.380	0.010	0.015	
с	0.090	0.230	0.004	0.009	
D	2.900	3.100	0.114	0.122	
E	2.900	3.100	0.114	0.122	
E1	4.750	5.050	0.187	0.199	
е	0.650 BSC		0.026 BSC		
L	0.400	0.800	0.016	0.031	
θ	0°	6°	0°	6°	



IMPORTANT NOTICE

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